

Vishay General Semiconductor

High-Current Density Surface Mount Schottky Rectifier





DO-220AA (SMP)

MAJOR RATINGS AND CHARACTERISTICS				
I _{F(AV)}	3.0 A			
V_{RRM}	50 V, 60 V			
I _{FSM}	45 A			
E _{AS}	11.25 mJ			
V _F at I _F = 3.0 A	0.61 V			
T _j max.	150 °C			

FEATURES

· Very low profile - typical height of 1.0 mm



- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency
- · Low thermal resistance
- Meets MSL level 1, per J-STD-020C, LF max peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

MECHANICAL DATA

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high

reliability grade (AEC Q101 qualified)

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS3P5	SS3P6	UNIT	
Device marking code		35	36		
Maximum repetive peak reverse voltage	V_{RRM}	50	60	V	
Maximum average forward rectified current (see Fig. 1)	I _{F(AV)}	3.0		Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	45		Α	
Non-repetitive avalanche energy at $I_{AS} = 1.5 \text{ A}$, $L = 10 \text{ mH}$, $T_j = 25 ^{\circ}\text{C}$	E _{AS}	11.25		mJ	
Voltage rate of change (rated V _R)	dv/dt	10000		V/us	
Operating junction and storage temperature range	$T_{J_{i}}T_{STG}$	- 55 to + 150		°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS	SYMBOL	TYP	MAX.	UNIT
Maximum instantaneous forward voltage (1)	at $I_F = 3 \text{ A}$, $T_j = 25 ^{\circ}\text{C}$ at $I_F = 3 ^{\circ}\text{A}$, $T_j = 125 ^{\circ}\text{C}$	V _F	0.71 0.61	0.78 0.65	>
Maximum reverse current at rated V _R ⁽¹⁾	T _j = 25 °C T _j = 125 °C	I _R	- 2.0	100 10	μA mA
Typical junction capacitance	at 4.0 V, 1 MHz	CJ	8	0	pF

Note

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

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SS3P5 & SS3P6

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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER SYMBOL SS3P5 SS3P6				UNIT
Typical thermal resistance ⁽¹⁾	$egin{array}{l} {\sf R}_{ heta {\sf JA}} \ {\sf R}_{ heta {\sf JL}} \ {\sf R}_{ heta {\sf JC}} \end{array}$	115 15 20		°C/W

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 15 x 15 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS3P6-E3/84A	0.024	84A	3000	7" Diameter Plastic Tape & Reel	
SS3P6-E3/85A	0.024	85A	10000	13" Diameter Plastic Tape & Reel	
SS3P6HE3/84A (1)	0.024	84A	3000	7" Diameter Plastic Tape & Reel	
SS3P6HE3/85A (1)	0.024	85A	10000	13" Diameter Plastic Tape & Reel	

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

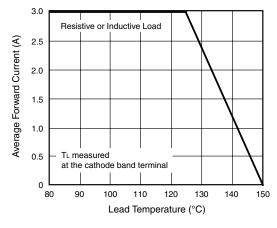


Figure 1. Forward Current Derating Curve

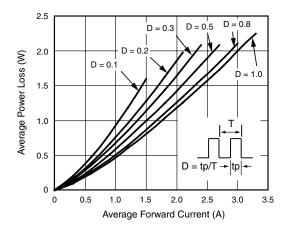


Figure 2. Forward Power Loss Characteristics





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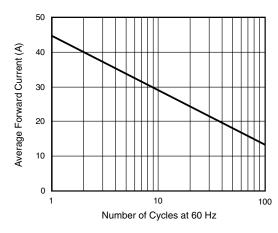


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

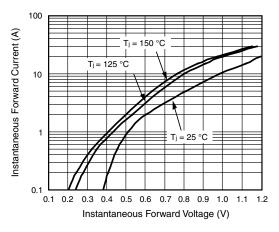


Figure 4. Typical Instantaneous Forward Characteristics

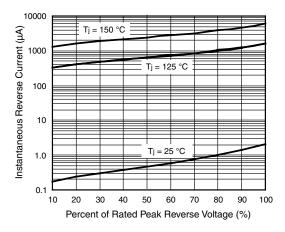


Figure 5. Typical Reverse Leakage Characteristics

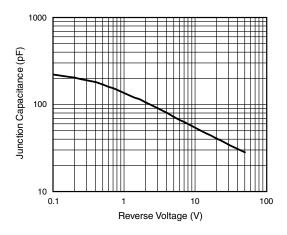


Figure 6. Typical Junction Capacitance

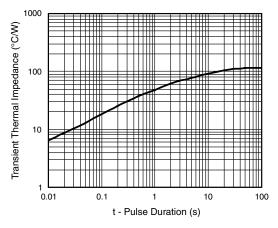


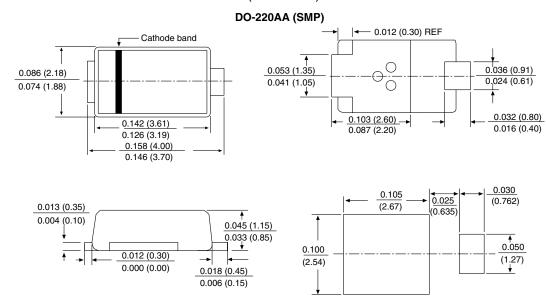
Figure 7. Typical Transient Thermal impedance

SS3P5 & SS3P6

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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